## **Product Preview**

# SMARTDISCRETES™ Internally Clamped, N-Channel IGBT

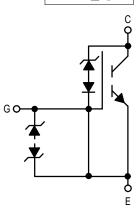
This Logic Level Insulated Gate Bipolar Transistor (IGBT) features Gate–Emitter ESD protection, Gate–Collector overvoltage protection from SMARTDISCRETES™ monolithic circuitry for usage as an **Ignition Coil Driver**.

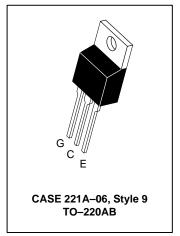
- Temperature Compensated Gate—Drain Clamp Limits Stress Applied to Load
- Integrated ESD Diode Protection
- Low Threshold Voltage to Interface Power Loads to Logic or Microprocessors
- Low Saturation Voltage
- · High Pulsed Current Capability



MGP20N14CL

20 AMPERES
VOLTAGE CLAMPED
N-CHANNEL IGBT
V<sub>Ce(on)</sub> = 1.9 VOLTS
135 VOLTS (CLAMPED)





## **MAXIMUM RATINGS** (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	VCES	CLAMPED	Vdc
Collector–Gate Voltage	VCGR	CLAMPED	Vdc
Gate–Emitter Voltage	VGE	CLAMPED	Vdc
Collector Current — Continuous @ $T_C = 25^{\circ}C$ — Single Pulsed ( $t_p = \pm 10 \mu s$ )	I <sub>C</sub>	20 60	Adc Apk
Total Power Dissipation @ T <sub>C</sub> = 25°C (TO–220) Derate Above 25°C	PD	150 1.0	Watts W/°C
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to 175	°C
Single Pulse Collector–Emitter Avalanche Energy @ Starting T <sub>J</sub> = 25°C (V <sub>CC</sub> = 80 V, V <sub>GE</sub> = 5 V, Peak I <sub>L</sub> = 10 A, L = 10 mH)	EAS	500	mJ

## THERMAL CHARACTERISTICS

Thermal Resistance — Junction to Case – (TO–220)  — Junction to Ambient	$R_{ heta JC} \ R_{ heta JA}$	1.0 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 5 seconds	TL	275	°C
Mounting Torque, 6–32 or M3 screw	10 lbf∙in (1.13 N∙m)		

SMARTDISCRETES and TMOS are trademarks of Motorola, Inc.

This document contains information on a new product. Specifications and information herein are subject to change without notice.

## MGP20N14CL

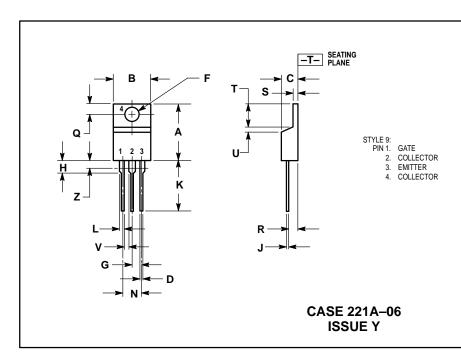
## $\textbf{ELECTRICAL CHARACTERISTICS} \ (T_C = 25^{\circ}\text{C unless otherwise noted})$

Cha	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS		•				
Clamp Voltage (IClamp = 10 mA, T <sub>J</sub> = -40 to 150°C)		BVCES	135			Vdc
Zero Gate Voltage Collector Current (VCE = 100 V, VGE = 0 V) (VCE = 100 V, VGE = 0 V, TJ = 150°C)		CES	_	_	10 100	μΑ
Gate-Emitter Clamp Voltage (IG =	1 mA)	BVGES	10	10		Vdc
Gate-Emitter Leakage Current (V	GE = ±5 V, V <sub>CE</sub> = 0 V)	IGES	_	_	1.0	μΑ
ON CHARACTERISTICS (1)		•				
Gate Threshold Voltage (VCE = VGE, IC = 1 mA) Threshold Temperature Coefficie	ent (Negative)	VCE(th)	1.0	1.5 4.4	2.0	V mV/°C
Collector–Emitter On–Voltage (V <sub>GE</sub> = 5 V, I <sub>C</sub> = 10 A) (V <sub>GE</sub> = 5 V, I <sub>C</sub> = 10 Adc, T <sub>J</sub> = 175°C)		VCE(on)	_		1.9 1.8	V
Forward Transconductance (V <sub>CE</sub> > 15 V, I <sub>C</sub> = 10 A)		9fs	8.0	15	_	Mhos
DYNAMIC CHARACTERISTICS		•				
Input Capacitance		C <sub>iss</sub>	_	430	600	pF
Output Capacitance	$(V_{CE} = 25 \text{ Vdc}, V_{GE} = 0 \text{ Vdc}, f = 1.0 \text{ MHz})$	C <sub>oss</sub>	_	182	250	1
Transfer Capacitance	,	C <sub>rss</sub>	_	48	100	1
SWITCHING CHARACTERISTICS	(1)	•				
Turn-On Delay Time		td(on)	_	TBD	TBD	ns
Rise Time	$(V_{CC} = 68 \text{ V}, I_{C} = 20 \text{ A},$	t <sub>r</sub>	_	TBD	TBD	
Turn-Off Delay Time	$V_{GE} = 5 \text{ V}, R_{G} = 9.1 \Omega$	t <sub>d</sub> (off)	_	TBD	TBD	1
Fall Time		t <sub>f</sub>	-	TBD	TBD	1
Total Gate Charge		Qg	-	14	20	nC
Gate-Emitter Charge	$(V_{CC} = 108 \text{ V, I}_{C} = 20 \text{ A,} $ $V_{GF} = 5 \text{ V})$	Qgs	_	3.0	_	1
Gate-Collector Charge	*GE - 3 */	Q <sub>qd</sub>	<u> </u>	6.0	_	1

Gate–Collector Charge

(1) Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.

## **PACKAGE DIMENSIONS**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

#### MGP20N14CL

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Motorola data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

#### How to reach us:

**USA/EUROPE/Locations Not Listed**: Motorola Literature Distribution; P.O. Box 5405, Denver, Colorado 80217. 303–675–2140 or 1–800–441–2447

Mfax™: RMFAX0@email.sps.mot.com – TOUCHTONE 602–244–6609 INTERNET: http://Design–NET.com

JAPAN: Nippon Motorola Ltd.; Tatsumi–SPD–JLDC, 6F Seibu–Butsuryu–Center, 3–14–2 Tatsumi Koto–Ku, Tokyo 135, Japan. 81–3–3521–8315

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298



MGP20N14CL/D